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KSP10

VHF/UHF transistor



1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|--|---------|-------|
| V _{CBO} | Collector-Base Voltage | 30 | V |
| V _{CEO} | Collector-Emitter Voltage | | V |
| V _{EBO} | Emitter-Base Voltage | 3.0 | V |
| P _C | Collector Power Dissipation (T _a =25°C) | 350 | mW |
| | Derate above 25°C | 2.8 | mW/°C |
| P _C | Collector Power Dissipation (T _C =25°C) | 1.0 | W |
| | Derate above 25°C | 8.0 | W/°C |
| TJ | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55~150 | °C |
| Rth(j-c) | Thermal Resistance, Junction to Case | 125 | °C/W |
| Rth(j-a) | Thermal Resistance, Junction to Ambient | 357 | °C/W |

Electrical Characteristics T_a =25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Max. | Units |
|-----------------------|--------------------------------------|---|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I _C =100μA, I _E =0 | 30 | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C =1mA, I _B =0 | 25 | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E =10μA, I _C =0 | 3.0 | | V |
| I _{CBO} | Collector Cut-off Current | V_{CB} =25V, I_{E} =0 | | 100 | nA |
| I _{EBO} | Emitter Cut-off Current | V _{EB} =2V, I _C =0 | | 100 | nA |
| h _{FE} | DC Current Gain | V _{CE} =10V, I _C =4mA | 60 | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =4mA, I _B =0.4mA | | 0.5 | V |
| V _{BE} (on) | Base-Emitter On Voltage | V _{CE} =10V, I _C =4mA | | 0.95 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} =10V, I _C =4mA, f=100MHz | 650 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} =10V, I _E =0, f=1MHz | | 0.7 | pF |
| C _{rb} | Collector Base Feedback Capacitance | V _{CB} =10V, I _E =0, f=1MHz | 0.35 | 0.65 | pF |
| C _{c·rbb′} | Collector Base Time Constant | V _{CB} =10V, I _C =4mA, f=31.8MHz | | 9.0 | ps |

^{*} Pulse Test: PW≤300μs, Duty Cycle≤2%

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Typical Characteristics

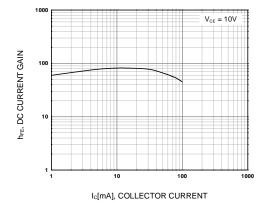


Figure 1. DC current Gain

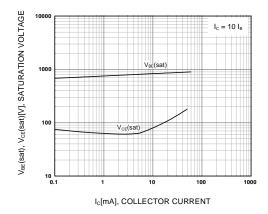


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

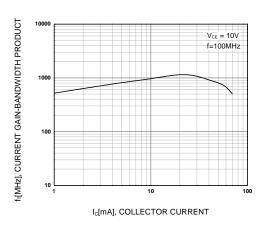


Figure 3. Current Gain Bandwidth Product

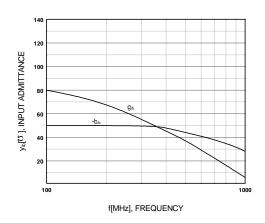


Figure 4. Rectangular Form

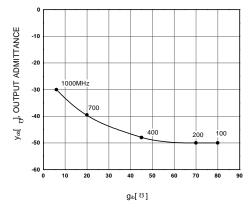


Figure 5. Polar Form

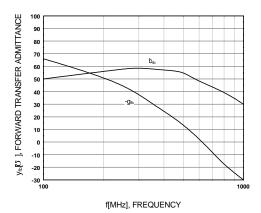


Figure 6. Rectangular Form

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Typical Characteristics (Continued)

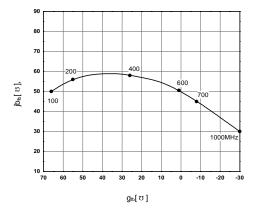


Figure 7. Polar Form

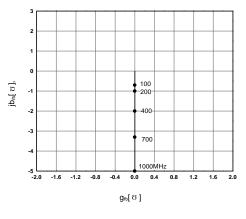


Figure 9. Polar Form

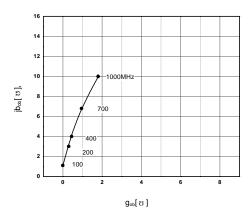


Figure 11. Polar Form

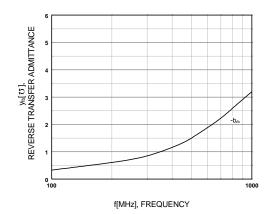


Figure 8. Rectangular Form

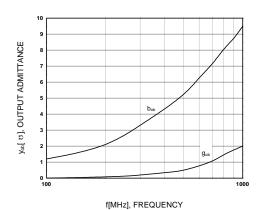
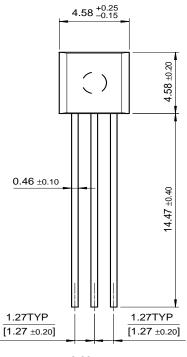


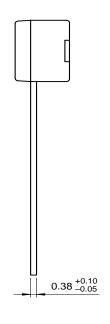
Figure 10. Rectangular Form

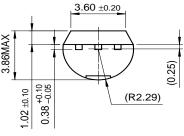
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Package Dimensions

TO-92







Dimensions in Millimeters

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